# Power MOSFET for 1-Cell Lithium-ion Battery Protection

## 12 V, 6.2 m $\Omega$ , 15 A, Dual N-Channel

This Power MOSFET features a low on-state resistance. This device is suitable for applications such as power switches of portable machines. Best suited for 1-cell lithium-ion battery applications.

### Features

- 2.5 V Drive
- Common-Drain Type
- ESD Diode-Protected Gate
- This device is Pb-Free, Halogen Free and RoHS Compliance

### Applications

• 1-Cell Lithium-ion Battery Charging and Discharging Switch

#### Specifications

### ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25°C)

Parameter	Symbol	Value	Unit
Source to Source Voltage	V <sub>SSS</sub>	12	V
Gate to Source Voltage	V <sub>GSS</sub>	±8	V
Source Current (DC)	۱ <sub>S</sub>	15	А
Source Current (Pulse) PW $\leq$ 10 $\mu$ s, duty cycle $\leq$ 1%	I <sub>SP</sub>	60	A
Total Dissipation (Note 1)	PT	1.4	W
Junction Temperature	Тj	150	°C
Storage Temperature	T <sub>stg</sub>	–55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

### THERMAL RESISTANCE RATINGS

Parameter	Symbol	Value	Unit
Junction to Ambient (Note 1)	$R_{\thetaJA}$	89.3	°C/W

1. Surface mounted on ceramic substrate (5000  $\text{mm}^2 \times 0.8$  mm).

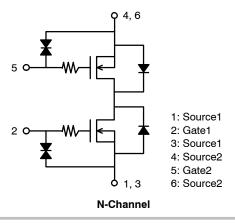


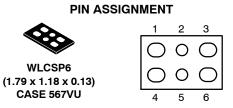
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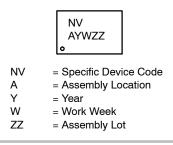
V <sub>SSS</sub>	R <sub>SS(ON)</sub> MAX	I <sub>S</sub> MAX
12 V	6.2 mΩ @ 4.5 V	15 A
	6.6 mΩ @ 3.8 V	
	8.0 mΩ @ 3.1 V	
	10.0 mΩ @ 2.5 V	

### **ELECTRICAL CONNECTION**





### MARKING DIAGRAM



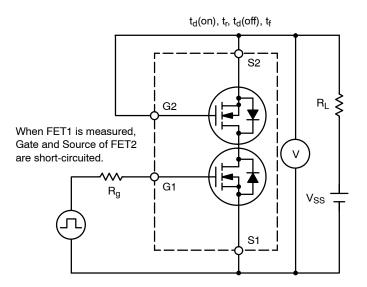
### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 2 of this data sheet.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>(BR)SSS</sub>	Source to Source Breakdown Voltage	e I <sub>S</sub> = 1 mA, V <sub>GS</sub> = 0 V	12	1		V
I <sub>SSS</sub>	Zero-Gate Voltage Source Current	$V_{SS} = 10 \text{ V}, V_{GS} = 0 \text{ V}$			1	μA
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{GS} = \pm 8 \text{ V}, \text{ V}_{SS} = 0 \text{ V}$			±1	μA
V <sub>GS</sub> (th)	Gate Threshold Voltage	V <sub>SS</sub> = 6 V, I <sub>S</sub> = 1 mA	0.4		1.3	V
R <sub>SS</sub> (on)	S(on) Static Source to Source On-State Resistance	$I_{S} = 5 \text{ A}, V_{GS} = 4.5 \text{ V}$	3.2	4.7	6.2	mΩ
		$I_{S} = 5 \text{ A}, V_{GS} = 3.8 \text{ V}$	3.5	5.0	6.6	mΩ
		$I_{S} = 5 \text{ A}, V_{GS} = 3.1 \text{ V}$	3.9	5.7	8.0	mΩ
		I <sub>S</sub> = 5 A, V <sub>GS</sub> = 2.5 V	4.5	6.6	10.0	mΩ
t <sub>d</sub> (on)	Turn-ON Delay Time	$V_{SS} = 5 V, V_{GS} = 3.8 V, I_{S} = 5 A$		5		μs
t <sub>r</sub>	Rise Time	Rg = 10 k $\Omega$ Switching Test Circuit		19		μs
t <sub>d</sub> (off)	Turn-OFF Delay Time	7		53		μs
t <sub>f</sub>	Fall Time			40		μs
Qg	Total Gate Charge	$V_{\rm SS}$ = 5 V, $V_{\rm GS}$ = 3.8 V, $I_{\rm S}$ = 5 A		16		nC
V <sub>F(S-S)</sub>	Forward Source to Source Voltage	I <sub>S</sub> = 3 A, V <sub>GS</sub> = 0 V		0.75	1.2	V

### **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ )

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.





#### **ORDERING INFORMATION**

Device	Marking	Package	Shipping <sup>†</sup> (Qty / Packing)
EFC2K101NUZTDG	NV	WLCSP6, 1.79 x 1.18 x 0.13 (Pb-Free / Halogen Free)	5,000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

### **TYPICAL CHARACTERISTICS**

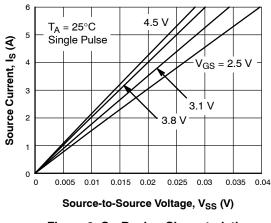
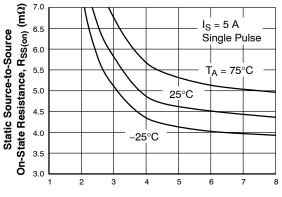


Figure 2. On-Region Characteristics



Gate-to-Source Voltage, V<sub>GS</sub> (V)

Figure 4. On-Resistance vs. Gate-to-Source Voltage

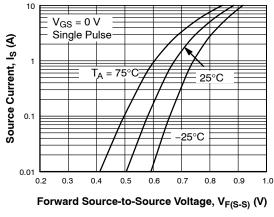


Figure 6. Forward Source-to-Source Voltage vs. Current

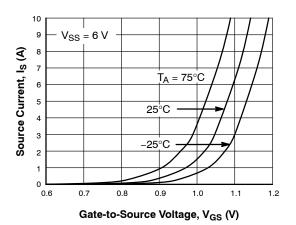
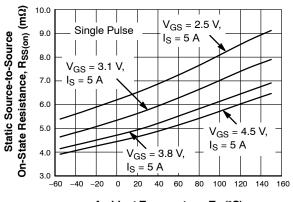


Figure 3. Transfer Characteristics



Ambient Temperature, T<sub>A</sub> (°C)



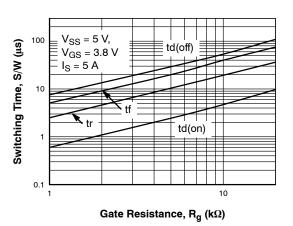


Figure 7. Switching Time vs. Gate Resistance

### **TYPICAL CHARACTERISTICS**

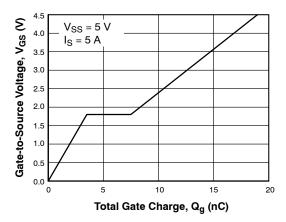


Figure 8. Gate-to-Source Voltage vs. Total Charge

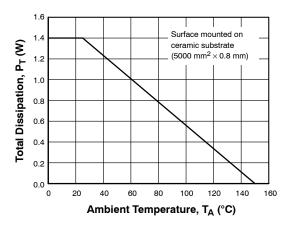


Figure 10. Total Dissipation vs. Temperature

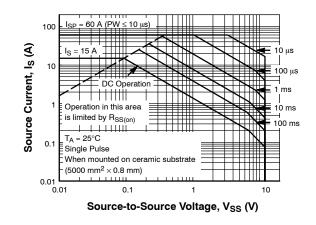


Figure 9. Safe Operating Area

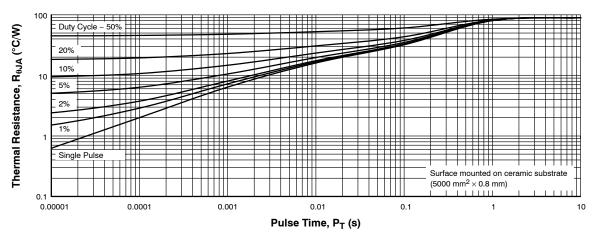


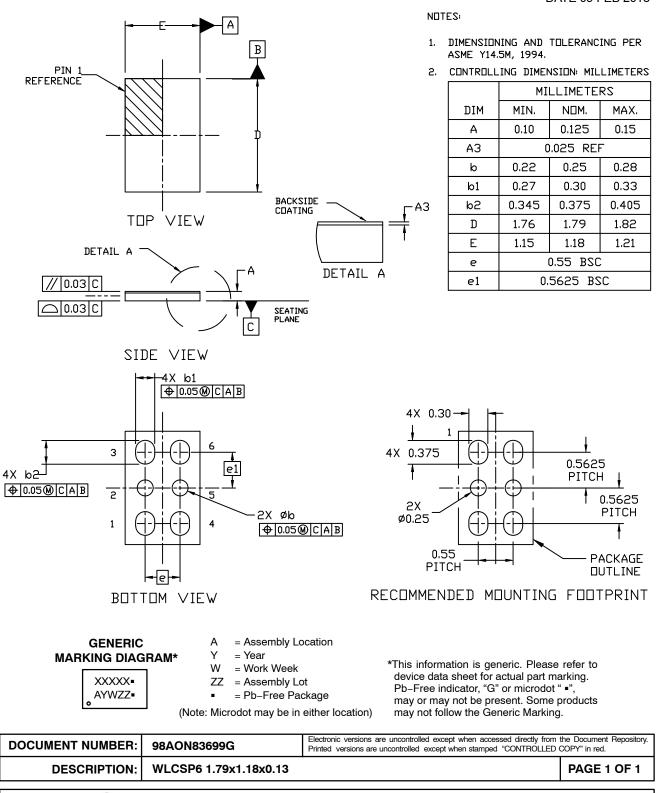
Figure 11. Thermal Response

Note on Usage: Since the EFC2K101NUZ is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.



WLCSP6 1.79x1.18x0.13 CASE 567VU ISSUE O

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